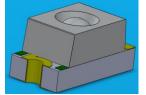


DATASHEET

1206 Package Phototransistor With Inner Lens





Features

- Fast response time
- High photo sensitivity
- Small junction capacitance
- Package in 8mm tape on 7" diameter reel
- Pb free
- The product itself will remain within RoHS compliant version.

Descriptions

• EAPST3015A0 is a phototransistor in miniature SMD package which is molded in a water clear plastic with flat top view lens. The device is Spectrally matched to visible and infrared emitting diode.

Applications

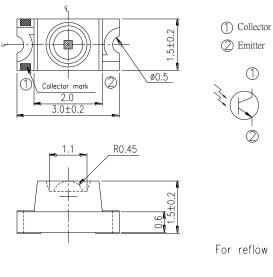
- Automatic door sensor
- Copier
- Game machine
- Infrared applied systm

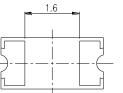
Device Selection Guide

Part Category	Chip Material	Lens Color
РТ	Silicon	Water clear

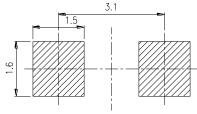


Package Dimensions









Notes: 1.All dimensions are in millimeters

2.Tolerances unless dimensions ±0.1mm

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V _{CEO}	30	V
Emitter-Collector-Voltage	V _{ECO}	5	V
Collector Current	I _C	20	mA
Operating Temperature	T _{opr}	-25 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +85	°C
Soldering Temperature *1	T _{sol}	260	°C
Power Dissipation at(or below) 25°C Free Air Temperature	P _d	75	mW

Notes: *1:Soldering time ≤ 5 seconds.

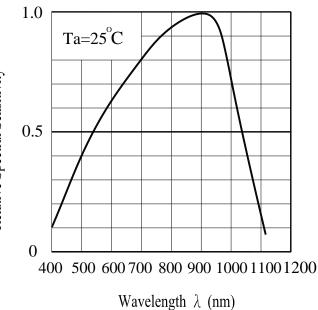
Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Rang Of Spectral Bandwidth	λ _{0.5}		530		1030	nm
Wavelength Of Peak Sensitivity	$\lambda_{ m P}$			940		nm
Collector-Emitter Breakdown Voltage	BV _{CEO}	$I_C=100\mu A$ Ee=0mW/cm ²	30			V
Emitter-Collector Breakdown Voltage	BV _{ECO}	$I_E=100\mu A$ Ee=0mW/cm ²	5			V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =2mA Ee=1m W/cm ²			0.4	V
Collector Dark Current	I _{CEO}	V _{CE} =20V Ee=0mW/cm ²			100	nA
On State Collector Current	I _{C(ON)}	V _{CE} =5V Ee=1mW /cm ²	0.3	0.8		mA

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Typical Electro-Optical Characteristics Curves

Fig.1 Spectral Sensitivity



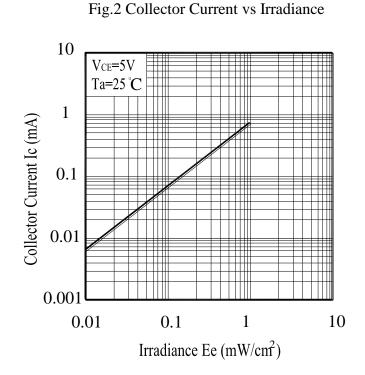


Fig.3 Collector Current vs. Collector-Emitter Voltage 3.5 3.0 Collector Current le (mA) 2.52.0 1.5Ee=1.00mW/cm² 1.00.50 0 1 2 3 4 Collector-Emitter Voltage Vct (V)

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Relative Spectral Sensitivity

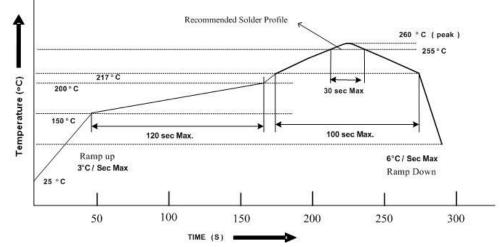


Precautions For Use

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

- 2. Storage
 - 2.1 Do not open moisture proof bag before the products are ready to use.
 - 2.2 Before opening the package, the LEDs should be kept at 30°C or less and 90%RH or less.
 - 2.3 The LEDs should be used within a year.
 - 2.4 After opening the package, the LEDs should be kept at 30°C or less and 60%RH or less.
 - 2.5 The LEDs should be used within 168 hours (7 days) after opening the package.
 - 2.6 If the moisture absorbent material (silica gel) has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the following conditions.Baking treatment : 60±5°C for Min. 24 hours.
- 3. Soldering Condition
- 3.1 Pb-free solder temperature profile



- 3.2 Reflow soldering should not be done more than two times.
- 3.3 When soldering, do not put stress on the LEDs during heating.
- 3.4 After soldering, do not warp the circuit board.

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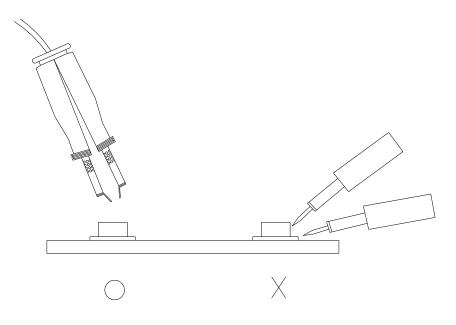
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4.Soldering Iron

Each terminal is to go to the tip of soldering iron temperature less than 350°C for 3 seconds within once in less than the soldering iron capacity 25W. Leave two seconds and more intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.

5.Repairing

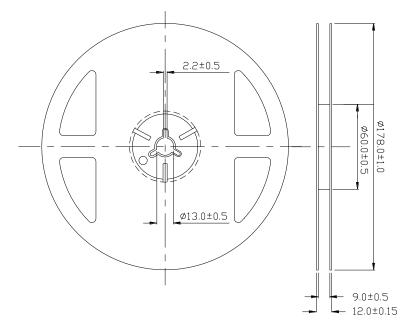
Repair should not be done after the LEDs have been soldered. When repairing is unavoidable, a double-head soldering iron should be used (as below figure). It should be confirmed beforehand whether the characteristics of the LEDs will or will not be damaged by repairing.



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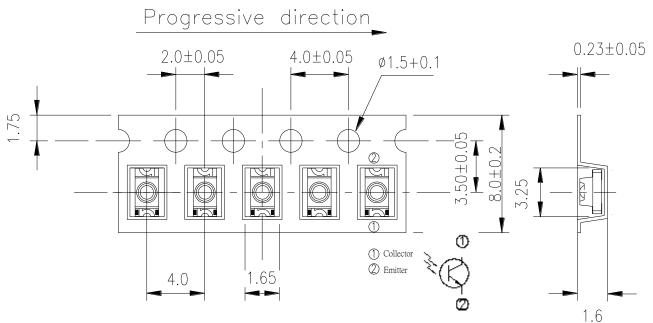


Package Dimensions



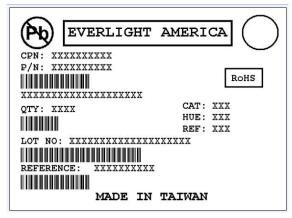
Note: The tolerances unless mentioned are ± 0.1 , unit=mm.

Carrier Taping Dimensions: Loaded Quantity 2000PCS/Reel



Note: The tolerances unless mentioned is ± 0.1 mm, Unit = mm

Label Form Specification



CPN: Customer's Production Number P/N : Production Number QTY: Packing Quantity CAT: Ranks HUE: Peak Wavelength REF: Reference LOT No: Lot Number

Notes

- 1. Above specification may be changed without notice. Everlight Americas will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. Everlight Americas assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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